EL2243D Die

Dual Fast Single-Supply Decompensated Op-Amp

Absolute Maximum Ratings (TA = 25°C)

Voltage between V+ and V-

Voltage between -IN or +IN Pins

36V

Voltage at -IN or +IN Pins **Output Current**

V+ to V-50 mA (Peak)

30 mA (Continuous)

Current into + IN, -IN

5 mA

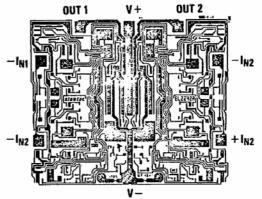
Important Note:

For AC electrical characteristics, refer to the typical electrical table and performance curves in the package data sheet. These characteristics are guaranteed but not tested in die form. Unless otherwise noted, all tests are pulsed tests, therefore $T_J = T_C = T_A$.

Test Procedure

100% production tested in wafer form. See remarks under Electrical Testing

in the General Die section.



DIE SIZE: 86 x 72 MILS

DC Electrical Characteristics $V_S = \pm 15$, $R_L = 1 \text{ k}\Omega$, $T_A = 25^{\circ}\text{C}$

Parameter	Description	Min	Тур	Max	Test Level	Units
v _{os}	Offset Voltage		1.5	5	# 100 1	mV
I_{B}	Bias Current		0.5	0.7	Reserved to the Misses	μΑ
Ios	Offset Current		0.01	0.1	21.00 1 .00 2.00 2.00 2.00 2.00 2.00 2.00 2.00	μΑ
V _{CM} +	Common Mode Range	12	13.3			v
v _{cm} -	Common Mode Range	-15	-15.3			v
A _{VOL}	Large Signal Voltage Gain (Note 1)	250	500		1	V/mV
CMRR	Common-Mode Rejection Ratio (Note 2)	80	100			dB
v _o	Output Voltage Swing R _L tied to V –	±12	± 13.5			v
		-14.98	-15			v
IO	Output Current (Note 4)	±15	±25	±50		mA
IS	Supply Current		8.2	10	I	mA
PSRR	Power Supply Rejection Ratio (Note 3)	80	100			dB

Note 1: $V_0 = \pm 10V$.

Note 2: Two tests are performed with $V_{CM} = 0V$ to -12V and $V_{CM} = 0V$ to 12V.

Note 3: Two tests are performed with V + = +3V, V - is changed from -2V to -27V. V - = -2V, V + is changed from 3V to

Note 4: The inputs are overdriven by $\pm 15V$ and the output R1 = 100Ω .